

ES1PB, ES1PC & ES1PD

RoHS

HALOGEN

FREE

AUTOMOTIVE

Available

Vishay General Semiconductor

High Current Density Surface Mount Ultrafast Rectifiers



DO-220AA (SMP)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	1.0 A			
V _{RRM}	100 V, 150 V, 200 V			
t _{rr}	15 ns			
V _F	0.92 V			
T _J max.	150 °C			

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of ac-to-dc and dc-to-dc converters for both consumer and automotive applications.

FEATURES

- Very low profile typical height of 1.0 mm
- · Ideal for automated placement
- · Glass passivated chip junction
- Ultrafast recovery times for high efficiency
 Levy forward valtage, levy power league.
- Low forward voltage, low power losses
- Low thermal resistance
- Meets MSL level 1 per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

MECHANICAL DATA

Case: DO-220AA (SMP)

Molding compound meets UL 94 V-0 flammability

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Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	ES1PB	ES1PC	ES1PD	UNIT	
Device marking code		EB	EC	ED		
Maximum repetitive peak reverse voltage	V _{RRM}	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	1.0			Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	30		А		
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150		°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage (1)	I _F = 0.6 A I _F = 1 A	T _J = 25 °C	V _F	0.865 0.920	٧	
Maximum reverse current at rated $V_R^{(2)}$		T _J = 25 °C T _J = 125 °C	I _R	5.0 500	μΑ	
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		t _{rr}	15	ns	
Typical reverse recovery time	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A}/\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	t _{rr}	25 30	ns	
Typical stored charge	$I_F = 1.0 \text{ A}, V_R = 30 \text{ V},$ $dI/dt = 50 \text{ A/}\mu\text{s}, I_{rr} = 10 \% I_{RM}$	T _J = 25 °C T _J = 100 °C	Q _{rr}	8 10	nC	
Typical junction capacitance	4.0 V, 1 MHz		C_J	10	pF	

Notes:

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	ES1PB	ES1PC	ES1PD	UNIT
(4)	$R_{ hetaJA}$		105		
Typical thermal resistance (1)	$R_{ hetaJL}$	15			°C/W
	$R_{ hetaJC}$		20		

Note:

⁽¹⁾ Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 5.0 mm x 5.0 mm copper pad areas. $R_{\theta JL}$ is measured at the terminal of cathode band. $R_{\theta JC}$ is measured at the top center of the body

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ES1PB-M3/84A	0.024	84A	3000	7" diameter plastic tape and reel	
ES1PB-M3/85A	0.024	85A	10 000	13" diameter plastic tape and reel	
ES1PBHM3/84A (1)	0.024	84A	3000	7" diameter plastic tape and reel	
ES1PBHM3/85A (1)	0.024	85A	10 000	13" diameter plastic tape and reel	

Note

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

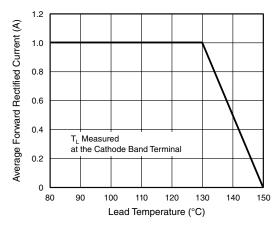


Figure 1. Maximum Forward Current Derating Curve

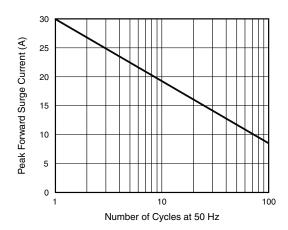


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

 $^{^{(1)}}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

⁽¹⁾ Automotive grade



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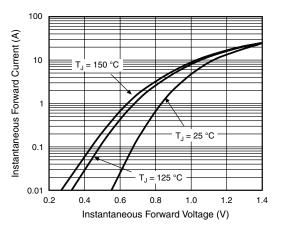


Figure 3. Typical Instantaneous Forward Characteristics

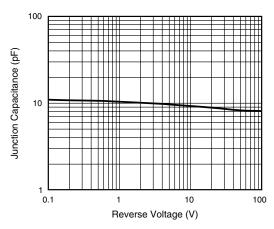


Figure 5. Typical Junction Capacitance

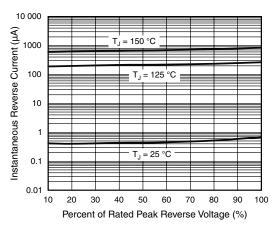


Figure 4. Typical Reverse Leakage Characteristics

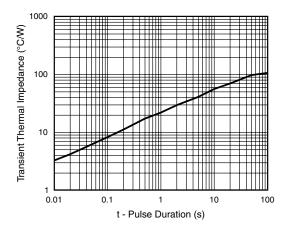
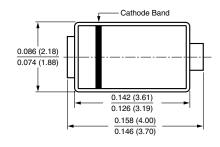
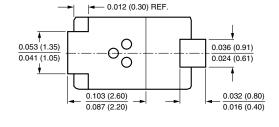


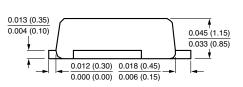
Figure 6. Typical Transient Thermal Impedance

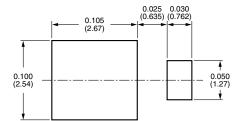
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-220AA (SMP)











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